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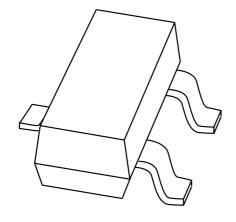
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



PBSS5250T 50 V, 2 A PNP low V_{CEsat} (BISS) transistor

Product data sheet 2003 Oct 09



50 V, 2 A PNP low V_{CEsat} (BISS) transistor

PBSS5250T

FEATURES

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability: I_C and I_{CM}
- Higher efficiency leading to less heat generation
- Reduced printed-circuit board requirements
- Cost effective alternative to MOSFETs in specific applications.

APPLICATIONS

- Power management
 - DC/DC converters
 - Supply line switching
 - Battery charger
 - LCD backlighting
- Peripheral drivers
 - Driver in low supply voltage applications (e.g. lamps and LEDs)
 - Inductive load driver (e.g. relays, buzzers and motors).

DESCRIPTION

PNP BISS transistor in a SOT23 plastic package offering ultra low V_{CEsat} and R_{CEsat} parameters.

MARKING

TYPE NUMBER	MARKING CODE(1)
PBSS5250T	3H*

Note

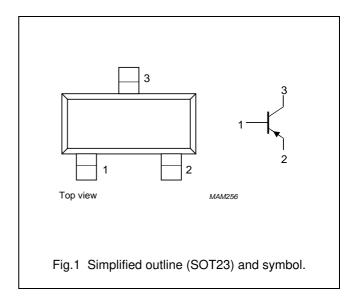
- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-50	V
I _C	collector current (DC)	-2	Α
I _{CM}	peak collector current	-3	Α
R _{CEsat}	equivalent on-resistance 150 n		mΩ

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
TTPE NOWIDER	NAME DESCRIPTION VERSION			
PBSS5250T	_	plastic surface mounted package; 3 leads SC		

50 V, 2 A PNP low V_{CEsat} (BISS) transistor

PBSS5250T

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-50	V
V_{CEO}	collector-emitter voltage	open base	_	-50	V
V _{EBO}	emitter-base voltage	open collector	_	- 5	V
I _C	collector current (DC)		-	-2	Α
I _{CM}	peak collector current	single peak	_	-3	Α
I _B	base current (DC)		_	-300	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1		300	mW
		T _{amb} ≤ 25 °C; note 2	_	480	mW
T _j	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

Notes

- 1. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; standard footprint.
- 2. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; mounting pad for collector 1 cm².

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	in free air; note 1	417	K/W
		in free air; note 2	260	K/W

Notes

- 1. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; standard footprint.
- 2. Device mounted on a FR4 printed-circuit board; single-sided copper; tinplated; mounting pad for collector 1 cm².

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CHARACTERISTICS

 T_{j} = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0$	_	_	-100	nA
		$V_{CB} = -50 \text{ V}; I_E = 0; T_j = 150 \text{ °C}$	_	_	-50	μΑ
I _{EBO}	emitter cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0$	_	_	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V}; I_{C} = 0.5 \text{ A}$	200	_	_	
		$V_{CE} = -2 \text{ V}; I_{C} = 1 \text{ A}; \text{ note 1}$	200	_	_	
		$V_{CE} = -2 \text{ V}; I_{C} = 2 \text{ A}; \text{ note 1}$	130	_	_	
V_{CEsat}	collector-emitter saturation	$I_C = -0.5 \text{ A}; I_B = -50 \text{ mA}$	_	_	-90	mV
	voltage	$I_C = -1 \text{ A}; I_B = -50 \text{ mA}$	_	_	-180	mV
		$I_C = -2 \text{ A}; I_B = -100 \text{ mA}$	_	_	-300	mV
R _{CEsat}	equivalent on-resistance	$I_C = -2 \text{ A}$; $I_B = -200 \text{ mA}$; note 1	-	-	150	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_C = -2 \text{ A}$; $I_B = -100 \text{ mA}$; note 1	_	_	-1.1	V
V_{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; I_{C} = -1 \text{ A}; \text{ note 1}$	-1.2	_	_	V
f _T	transition frequency	$I_C = -100 \text{ mA}; V_{CE} = -5 \text{ V};$ f = 100 MHz	100	_	_	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$	_	_	35	pF

Note

1. Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

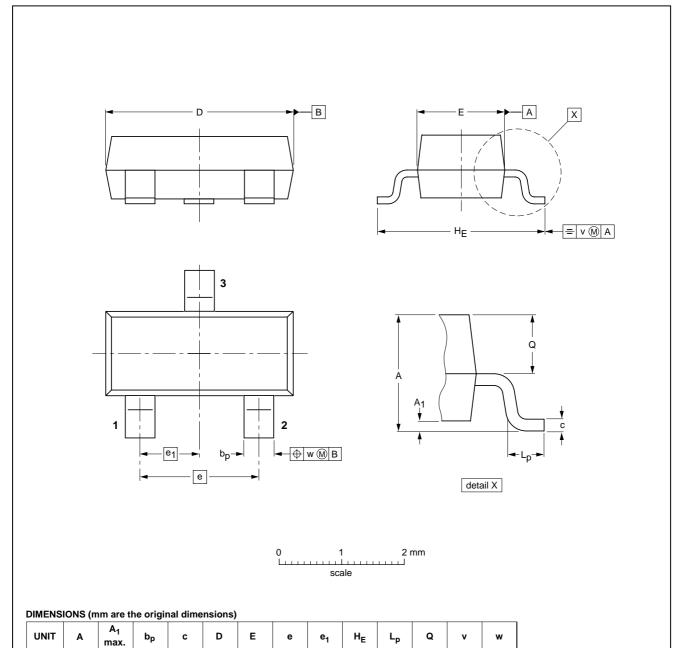
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PBSS5250T

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



OUTLINE	REFERENCES		EUROPEAN	ICCUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION ISSUE DA	
SOT23		TO-236AB				97-02-28 99-09-13

0.95

0.45

0.15

0.55

0.45

0.1

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0.48

0.38

0.1

mm

0.15

0.09

3.0

2.8

1.4

1.9

50 V, 2 A PNP low V_{CEsat} (BISS) transistor

PBSS5250T

DATA SHEET STATUS

DOCUMENT STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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NXP Semiconductors

Customer notification

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Contact information

For additional information please visit: http://www.nxp.com

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